

**A GENERALIZED SPACE MAPPING TABLEAU APPROACH  
TO MICROWAVE DEVICE MODELING**

M.A. Ismail

SOS-98-43-V

December 1998

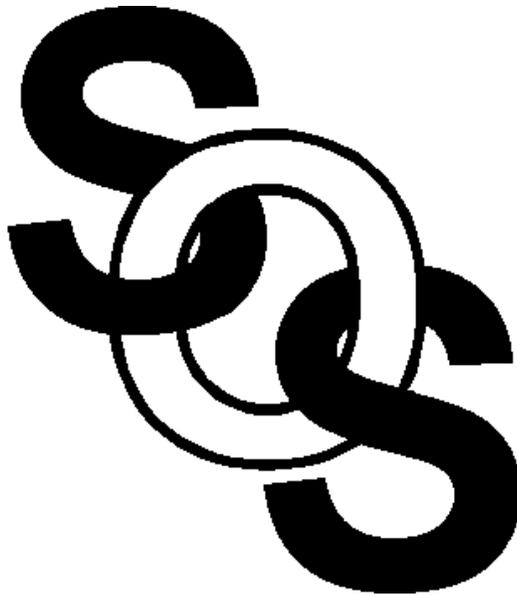
© M.A. Ismail 1998

No part of this document may be copied, translated, transcribed or entered in any form into any machine without written permission. Address inquiries in this regard to Dr. J.W. Bandler. Excerpts may be quoted for scholarly purposes with full acknowledgement of source. This document may not be lent or circulated without this title page and its original cover.

# **A GENERALIZED SPACE MAPPING APPROACH TO MICROWAVE CIRCUITS AND DEVICE MODELING**

M.A. Ismail

Simulation Optimization Systems Research Laboratory  
and Department of Electrical and Computer Engineering  
McMaster University, Hamilton, Canada L8S 4L7



presented at

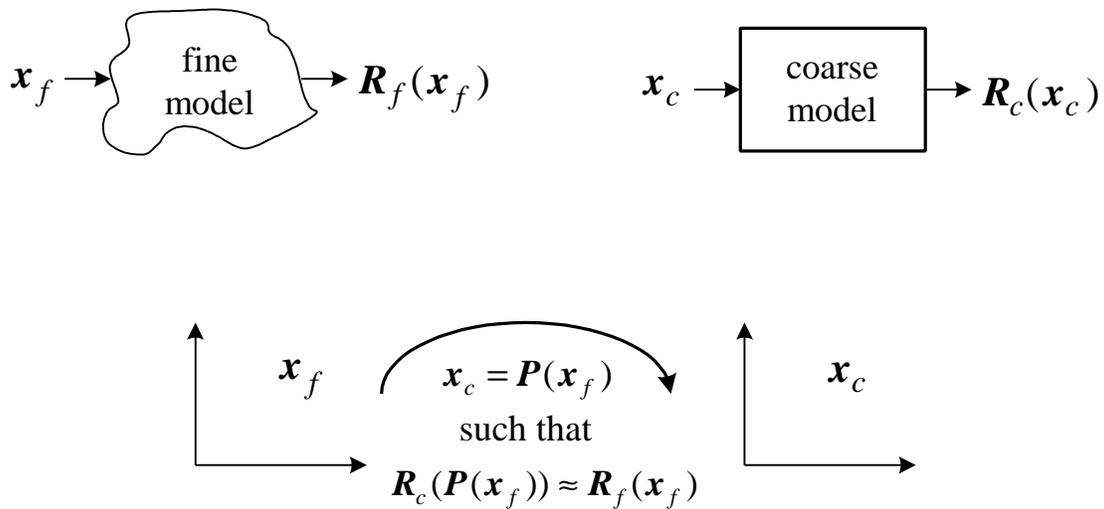
SOS Research Laboratory Meeting, Hamilton, December, 1998



## Basic Concepts

Space Mapping (SM) is a powerful tool for circuit design and optimization

two model types are usually defined in the SM: a “coarse” model, typically an empirical model, and a “fine” model, typically a full wave electromagnetic simulator





## **Generalized Space Mapping (GSM)**

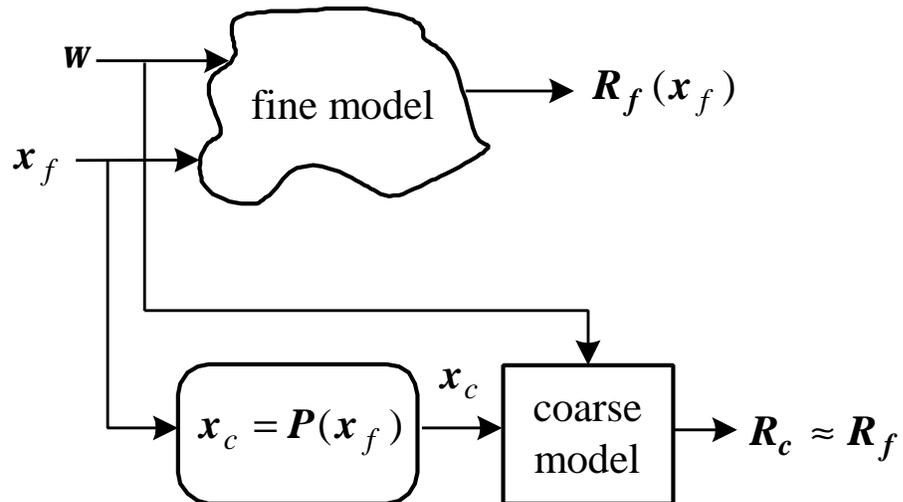
GSM is a comprehensive framework to engineering device modeling

GSM exploits the Space Mapping (SM), the Frequency Space Mapping (FSM) and the Multiple Space Mapping (MSM) concepts to build a new engineering device modeling framework

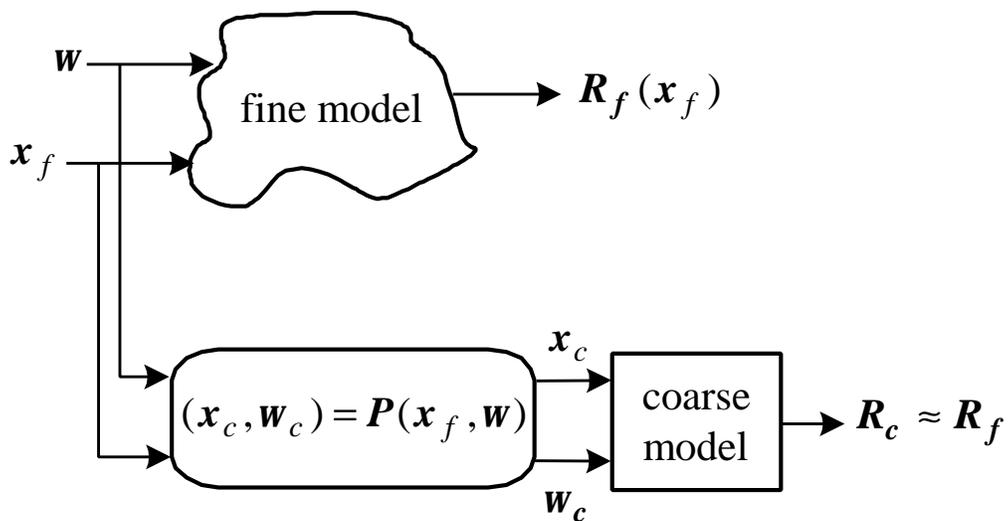
two cases are considered: the basic Space Mapping Super Model (SMSM) concept and the Frequency-Space Mapping Super Model (FSMSM) concept



## Space Mapping Super Model (SMSM)



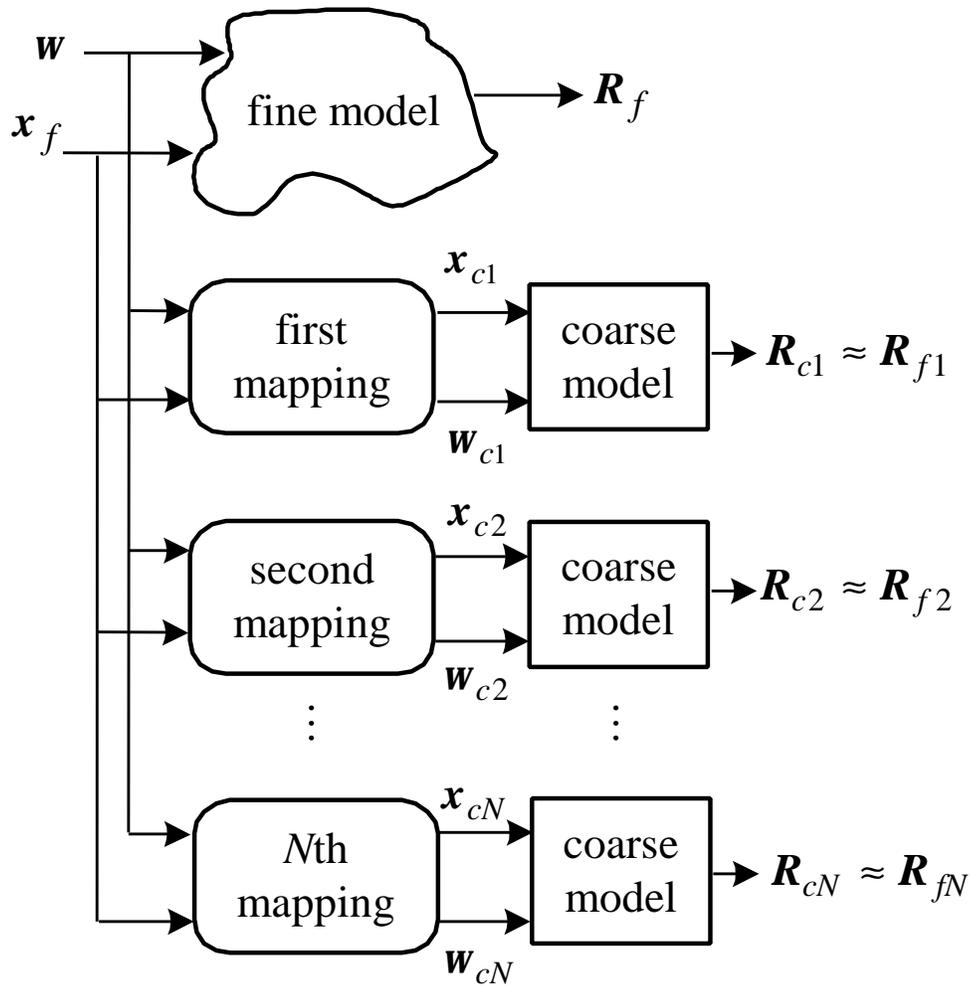
## Frequency-Space Mapping Super Model (FSMSM)





## Multiple Space Mapping (MSM) Concept

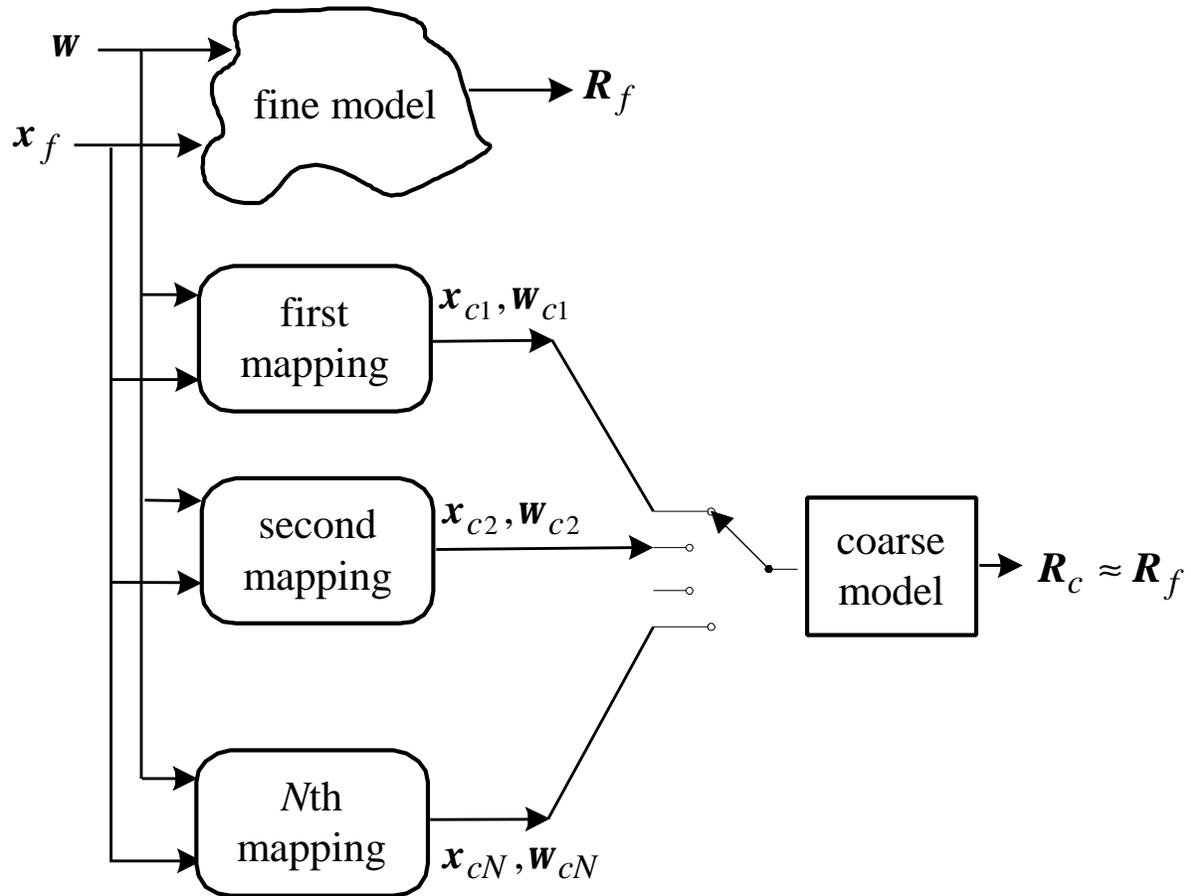
MSM for different responses





## Multiple Space Mapping (MSM) Concept

MSM for different frequency ranges





## Mathematical Formulation for GSM

the  $k$ th mapping targeting the sub-response  $\mathbf{R}_k$  or the response  $\mathbf{R}$  in the  $k$ th frequency sub-range is given by

$$(\mathbf{x}_{ck}, \mathbf{w}_{ck}) = \mathbf{P}_k(\mathbf{x}_f, \mathbf{w})$$

or, in matrix form, assuming a linear mapping,

$$\begin{bmatrix} \mathbf{x}_{ck} \\ \mathbf{w}_{ck} \end{bmatrix} = \begin{bmatrix} \mathbf{c}_k \\ \mathbf{d}_k \end{bmatrix} + \begin{bmatrix} \mathbf{B}_k & \mathbf{s}_k \\ \mathbf{t}_k^T & \mathbf{s}_k \end{bmatrix} \begin{bmatrix} \mathbf{x}_f \\ \mathbf{w} \end{bmatrix}$$

the mapping parameters  $\{\mathbf{c}_k, \mathbf{B}_k, \mathbf{s}_k, \mathbf{t}_k, \mathbf{s}_k, \mathbf{d}_k\}$  can be evaluated, directly or indirectly, by solving the optimization problem

$$\min_{\mathbf{c}_k, \mathbf{B}_k, \mathbf{s}_k, \mathbf{t}_k, \mathbf{s}_k, \mathbf{d}_k} \left\| \begin{bmatrix} \mathbf{e}_{k1}^T & \mathbf{e}_{k2}^T & \cdots & \mathbf{e}_{km}^T \end{bmatrix}^T \right\|$$

where  $m$  is the number of base points selected in the fine model space and  $\mathbf{e}_{kj}$  is an error vector given by

$$\mathbf{e}_{kj} = \mathbf{R}_f(\mathbf{x}_f^{(j)}, \mathbf{w}) - \mathbf{R}_c(\mathbf{x}_{ck}^{(j)}, \mathbf{w}_{ck}), \quad j = 1, 2, \dots, m$$

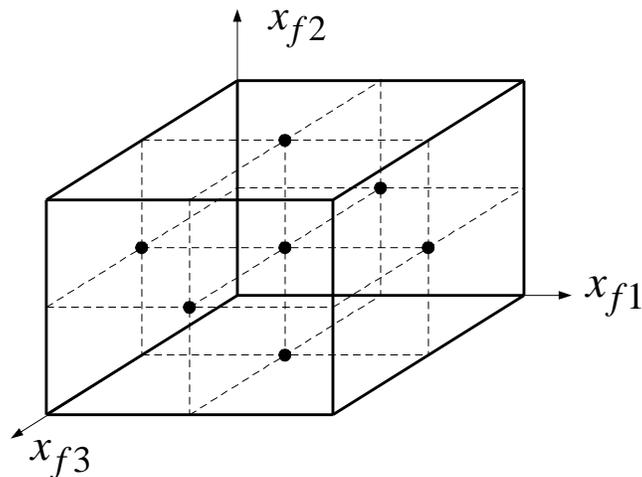
an important variation of the mapping is to use the inverse of the frequency variable (which is proportional to the wavelength) instead of the frequency itself



## An Implementation of SMSM and FSMSM

the SMSM for the  $k$ th mapping can be evaluated through the following steps

choose a set of  $m$  base points  $\{\mathbf{x}_f^{(j)}, j = 1, 2, \dots, m\}$  in the fine model space



for each base point  $\mathbf{x}_f^{(j)}$  the corresponding point  $\mathbf{x}_c^{(j)}$  in the coarse model space can be obtained by solving a parameter extraction problem

the  $k$ th mapping parameters  $\mathbf{c}_k, \mathbf{B}_k$  can then be evaluated by least-squares

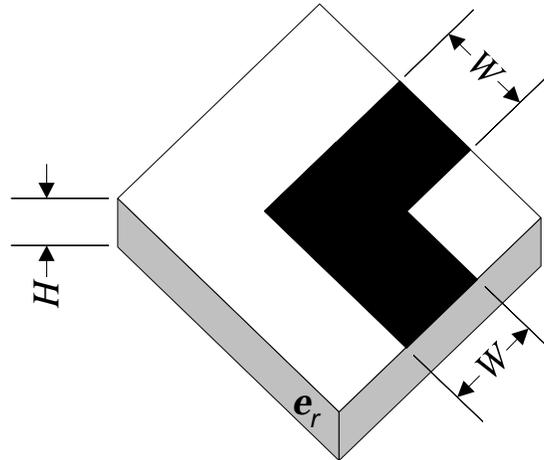
in FSMSM we evaluate  $\mathbf{c}_k, \mathbf{B}_k$  as in SMSM and then obtain  $s_k, d_k$  by solving

$$\min_{s_k, t_k, \mathbf{s}_k, \mathbf{d}_k} \left\| \begin{bmatrix} \mathbf{e}_{k1}^T & \mathbf{e}_{k2}^T & \dots & \mathbf{e}_{km}^T \end{bmatrix}^T \right\|$$

considering  $\mathbf{c}_k, \mathbf{B}_k$  fixed



## FSMSM for Microstrip Right Angle Bend



Parameter	Minimum	Maximum
$W$	20 mil	30 mil
$H$	8 mil	16 mil
$e_r$	8	10

the fine model is analyzed by Sonnet's *em* and the "coarse" model is Jansen empirical model

the fine model parameters are given by

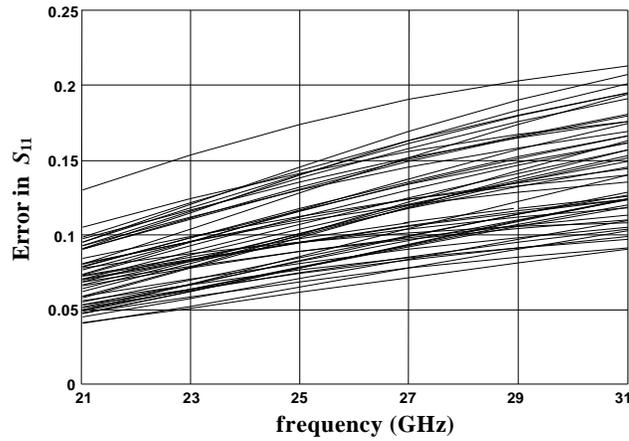
$$\mathbf{x}_f = [W \ H \ e_r]^T$$

the coarse model parameters are given by

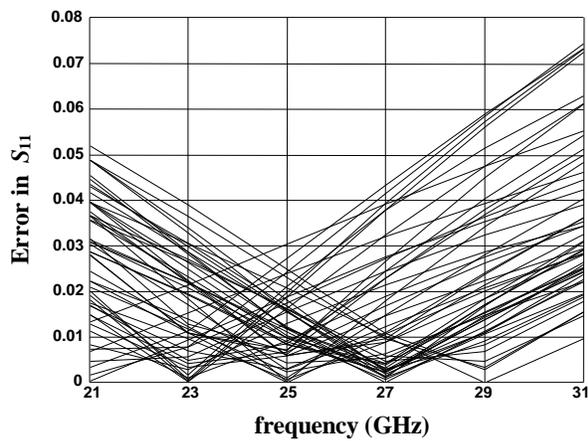
$$\mathbf{x}_c = [W_1 \ H_1 \ e_{r1}]^T$$



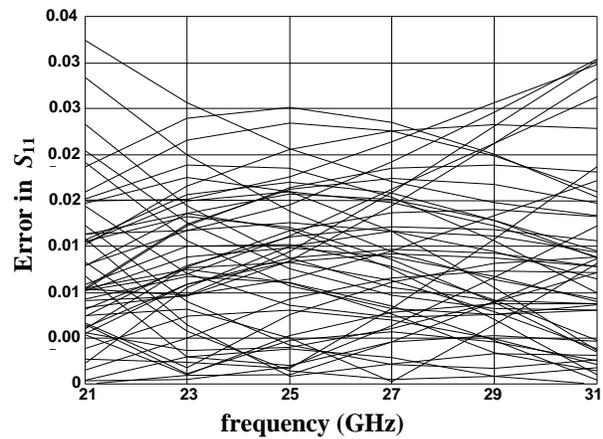
## FSMSM for the Right Angle Bend



(before applying SMSG or FSMSG)



(after applying SMSG)



(after applying FSMSG)



## MSM-FSMSM for the Right Angle Bend

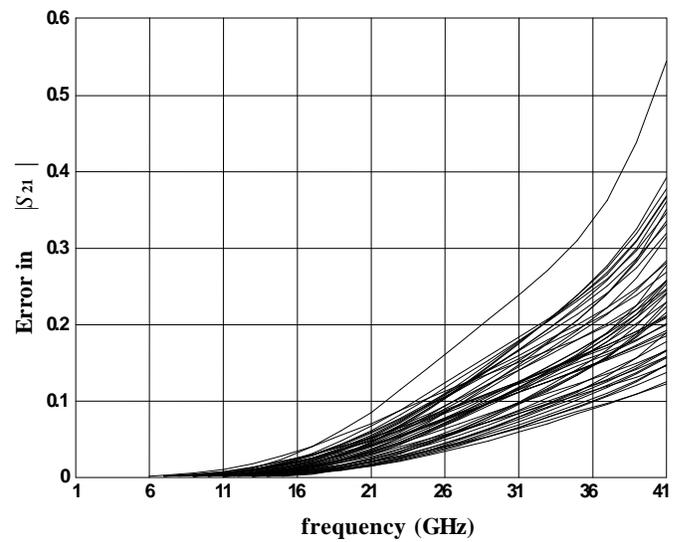
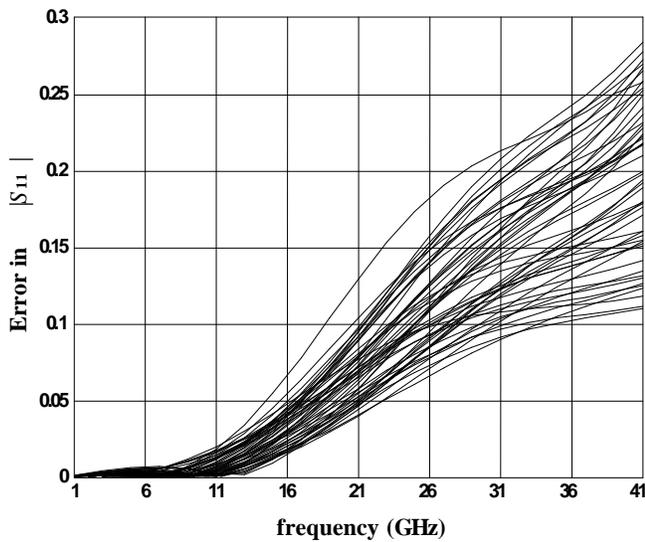
Frequency range	$B_k$	$c_k$	$s_k$	$d_k$
1 GHz to 11 GHz	1	0	1	0
11 GHz to 21 GHz	$\begin{bmatrix} 1.81627 & 0.81981 & 0.91555 \\ 0.44352 & 0.30230 & 0.02315 \\ 0.10138 & -0.27993 & 0.33187 \end{bmatrix}$	$\begin{bmatrix} -22.7 \\ -3.822 \\ 1.87 \end{bmatrix}$	1.297	-4.765
21 GHz to 31 GHz	$\begin{bmatrix} 2.33221 & 1.98365 & 2.17360 \\ 0.53802 & 0.54226 & 0.45435 \\ 0.09298 & -0.29729 & 0.28768 \end{bmatrix}$	$\begin{bmatrix} -49.41 \\ -9.324 \\ 2.49 \end{bmatrix}$	1.452	-10.964
31 GHz to 35 GHz	$\begin{bmatrix} 2.77533 & 3.06006 & 2.92395 \\ 0.69924 & 0.81860 & 0.59300 \\ 0.11844 & -0.31135 & 0.26187 \end{bmatrix}$	$\begin{bmatrix} -71.5 \\ -15.2 \\ 2.19 \end{bmatrix}$	1.446	-15.765
35 GHz to 41 GHz	$\begin{bmatrix} 3.94219 & 4.61833 & 4.95400 \\ 1.12763 & 1.33404 & 1.46545 \\ 0.11454 & -0.30212 & 0.26215 \end{bmatrix}$	$\begin{bmatrix} -125.4 \\ -36.13 \\ 1.87 \end{bmatrix}$	1.977	-36.335

---

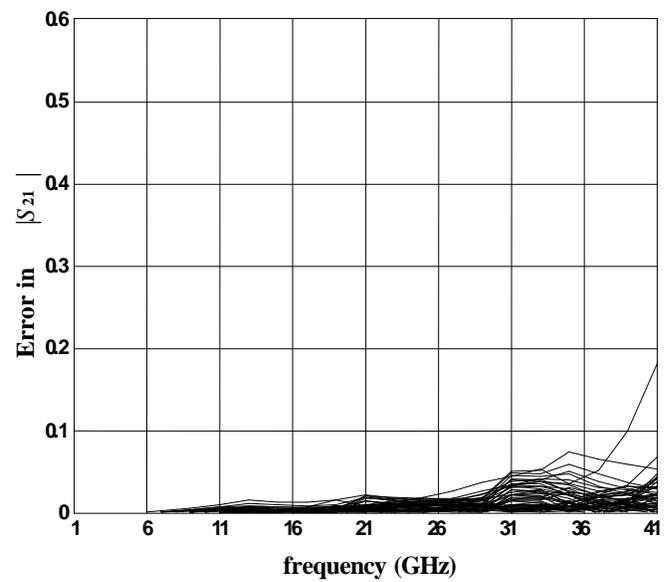
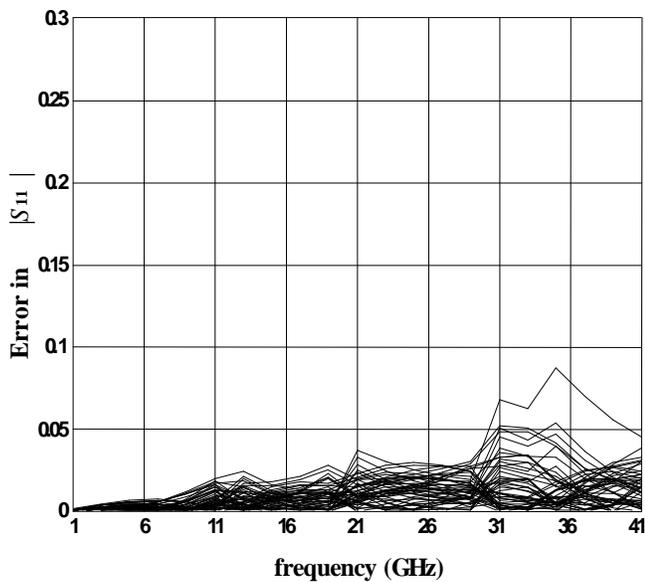


## MSM-FSMSM for the Right Angle Bend

the error in  $|S_{11}|$  and  $|S_{21}|$  before applying MSM-FSMSM



the error in  $|S_{11}|$  and  $|S_{21}|$  after applying MSM-FSMSM





## Conclusions

we introduce a comprehensive framework called Generalized Space Mapping (GSM) to engineering device modeling

In GSM we utilize a few relevant full-wave EM simulations to match the responses of the fine model and the coarse model over a designable region of parameters and frequency

GSM generalizes the Space Mapping (SM), the Frequency Space Mapping (FSM) and the Multiple Space Mapping (MSM) concepts to build a new engineering device modeling framework

two fundamental concepts are presented: one is a basic Space Mapping Super Model (SMSM) and the other is a basic Frequency-Space Mapping Super Model (FSMSM)

MSM can be combined with SMSM and FSMSM to provide a powerful and reliable modeling tool for microwave devices

more research is being carried out to efficiently evaluate the mappings defined in GSM and to apply the generic GSM concept to enhance the accuracy of microwave circuits